NSN 5961-01-129-7729

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-129-7729 **Inclosure Material:** Glass **Overall Length:** 4.57 millimeters **Terminal Length:** 25.40 millimeters **Overall Diameter:** 1.88 millimeters **Function For Which Designed:** Switching **End Application:** C130 awads 36378; countermeasure set; radar set; fire control set; phoenix missile; sonar dome rubber windows; tactical air opns module; computar display set **Mounting Method: Terminal Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 breakdown voltage, dc and 175.0 working peak reverse voltage **Current Rating Per Characteristic:** 100.00 milliamperes forward current, total rms megahertz **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** Weapon system essential **Test Data Document:** 81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 81349-mil-prf-19500/169 government specification Shelf Life: N/a **Unit Of Measure:**

Mil-std (military Standard):

Demilitarization:

No Fiig: A110a0